



CPH6355

P-Channel Power MOSFET -30V, -3A, 169mΩ, Single CPH6

ON Semiconductor®

http://onsemi.com

Features

- ON-resistance $R_{DS(on)} = 130\text{m}\Omega$ (typ.)
- 4V drive
- Halogen free compliance

Specifications

Absolute Maximum Ratings at $T_a=25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Drain to Source Voltage	V_{DSS}		-30	V
Gate to Source Voltage	V_{GSS}		± 20	V
Drain Current (DC)	I_D		-3	A
Drain Current (Pulse)	I_{DP}	$PW \leq 10\mu\text{s}$, duty cycle $\leq 1\%$	-12	A
Allowable Power Dissipation	P_D	When mounted on ceramic substrate (1500mm 2 x 0.8mm)	1.6	W
Channel Temperature	T_{ch}		150	$^\circ\text{C}$
Storage Temperature	T_{stg}		-55 to +150	$^\circ\text{C}$

This product is designed to "ESD immunity < 200V**", so please take care when handling.

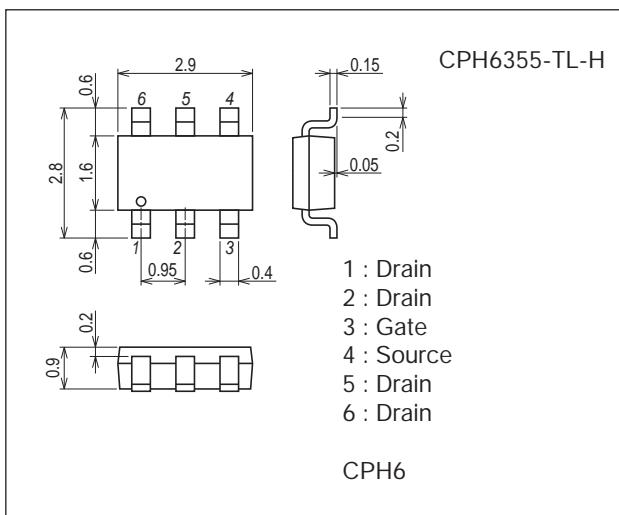
* Machine Model

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit : mm (typ)

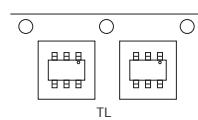
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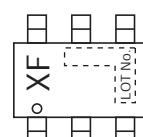
Product & Package Information

- Package : CPH6
- JEITA, JEDEC : SC-74, SOT-26, SOT-457
- Minimum Packing Quantity : 3,000 pcs./reel

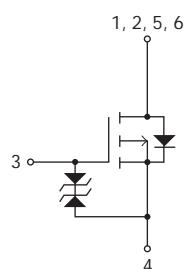
Packing Type: TL



Marking



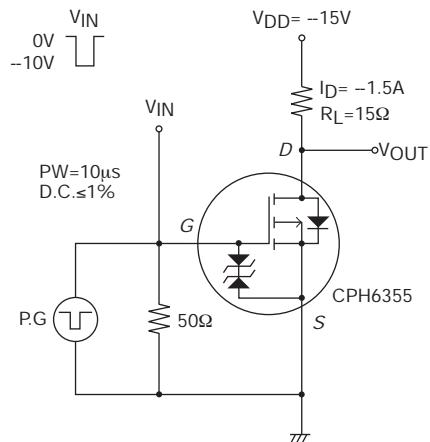
Electrical Connection



Electrical Characteristics at $T_a=25^\circ\text{C}$

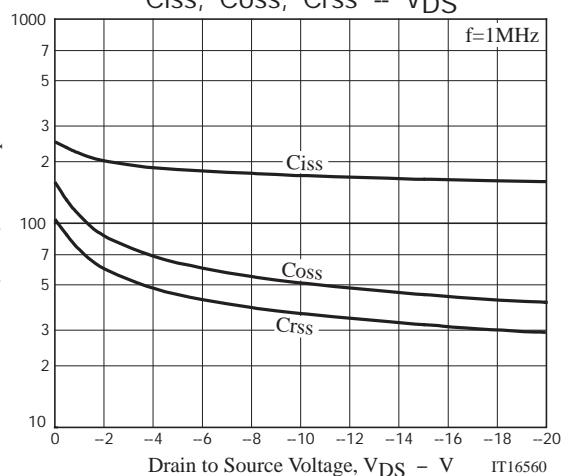
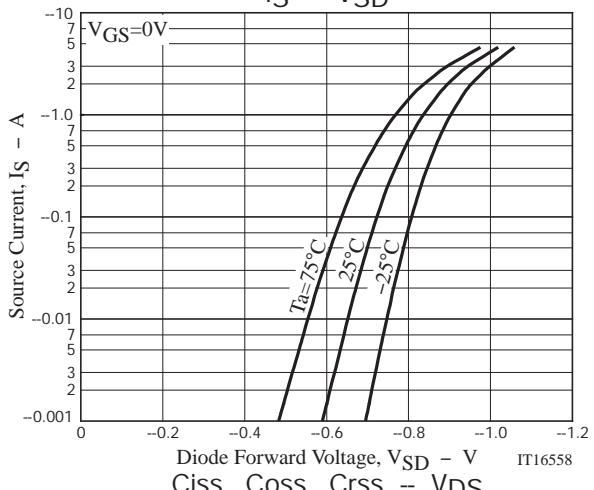
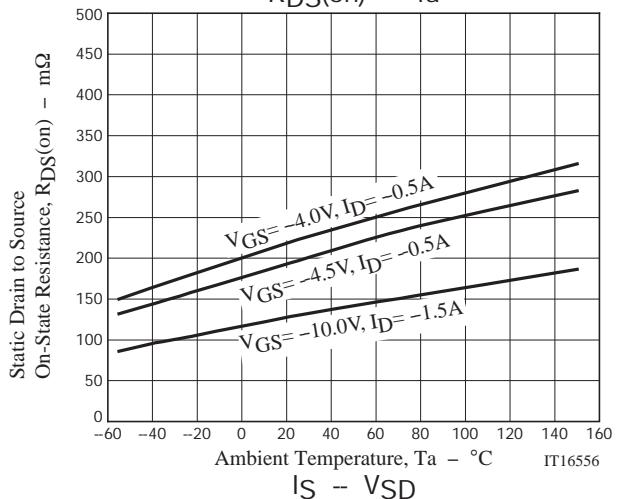
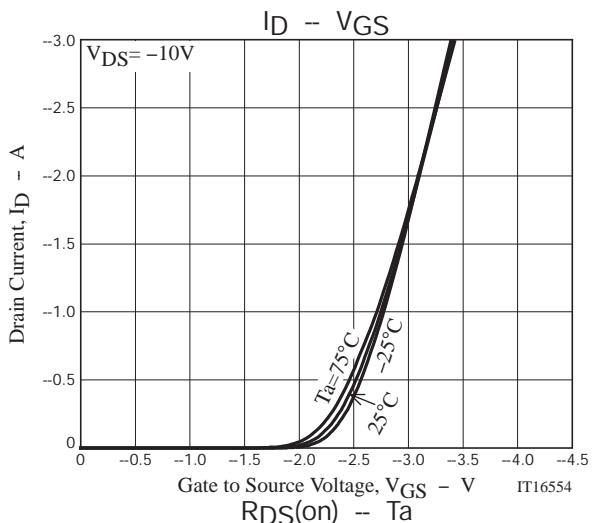
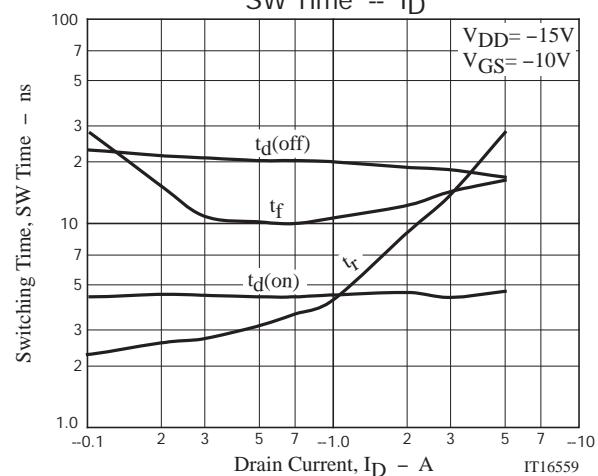
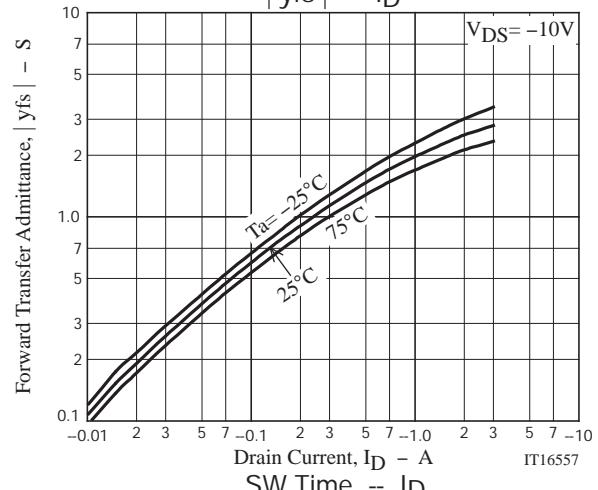
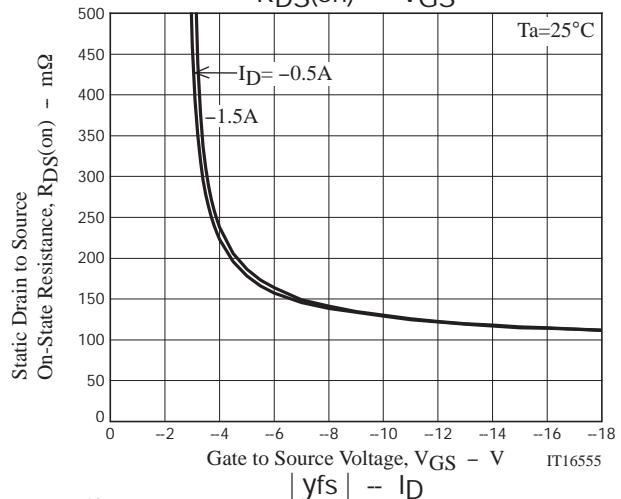
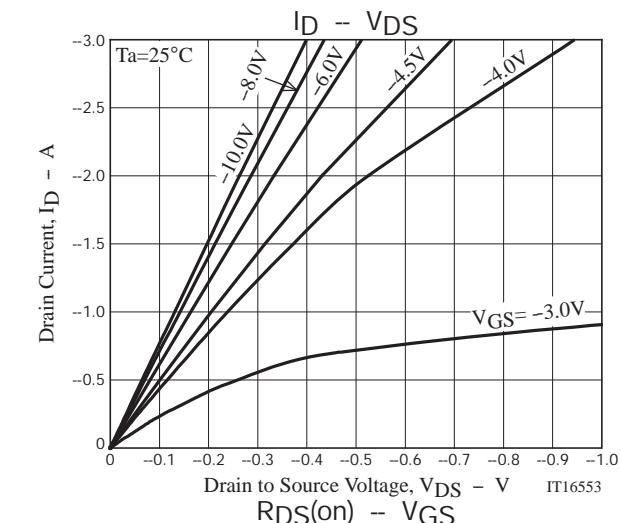
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain to Source Breakdown Voltage	$V_{(\text{BR})\text{DSS}}$	$I_D=-1\text{mA}, V_{GS}=0\text{V}$	-30			V
Zero-Gate Voltage Drain Current	I_{DSS}	$V_{DS}=-30\text{V}, V_{GS}=0\text{V}$			-1	μA
Gate to Source Leakage Current	I_{GSS}	$V_{GS}=\pm 16\text{V}, V_{DS}=0\text{V}$			± 10	μA
Cutoff Voltage	$V_{GS(\text{off})}$	$V_{DS}=-10\text{V}, I_D=-1\text{mA}$	-1.2		-2.6	V
Forward Transfer Admittance	$ y_{fs} $	$V_{DS}=-10\text{V}, I_D=-1.5\text{A}$		2.3		S
Static Drain to Source On-State Resistance	$R_{DS(\text{on})1}$	$I_D=-1.5\text{A}, V_{GS}=-10\text{V}$		130	169	$\text{m}\Omega$
	$R_{DS(\text{on})2}$	$I_D=-0.5\text{A}, V_{GS}=-4.5\text{V}$		197	276	$\text{m}\Omega$
	$R_{DS(\text{on})3}$	$I_D=-0.5\text{A}, V_{GS}=-4\text{V}$		223	313	$\text{m}\Omega$
Input Capacitance	C_{iss}	$V_{DS}=-10\text{V}, f=1\text{MHz}$		172		pF
Output Capacitance	C_{oss}			51		pF
Reverse Transfer Capacitance	C_{rss}			36		pF
Turn-ON Delay Time	$t_{\text{d}(\text{on})}$	See specified Test Circuit.		4.6		ns
Rise Time	t_r			6.6		ns
Turn-OFF Delay Time	$t_{\text{d}(\text{off})}$			19.4		ns
Fall Time	t_f			11.4		ns
Total Gate Charge	Q_g	$V_{DS}=-15\text{V}, V_{GS}=-10\text{V}, I_D=-3\text{A}$		3.9		nC
Gate to Source Charge	Q_{gs}			0.6		nC
Gate to Drain "Miller" Charge	Q_{gd}			0.8		nC
Diode Forward Voltage	V_{SD}	$I_S=-3\text{A}, V_{GS}=0\text{V}$		-0.95	-1.5	V

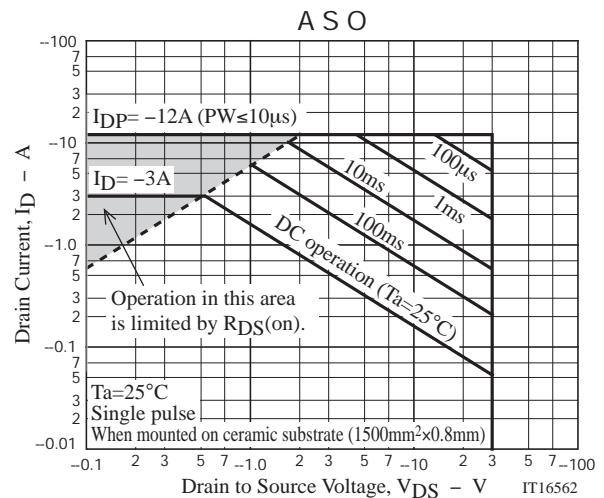
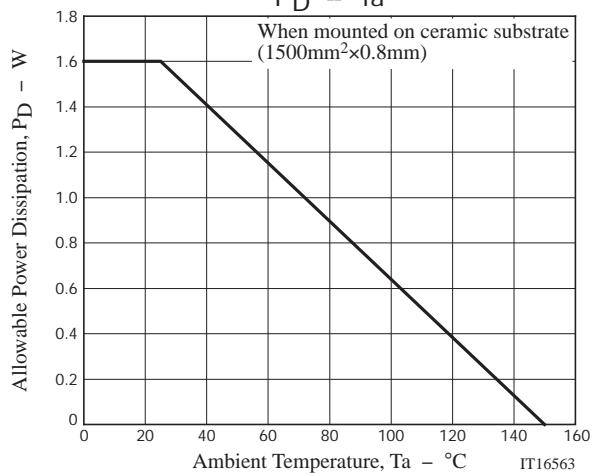
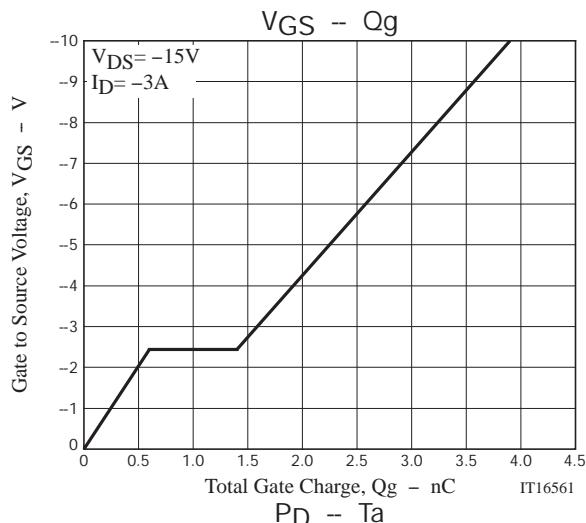
Switching Time Test Circuit



Ordering Information

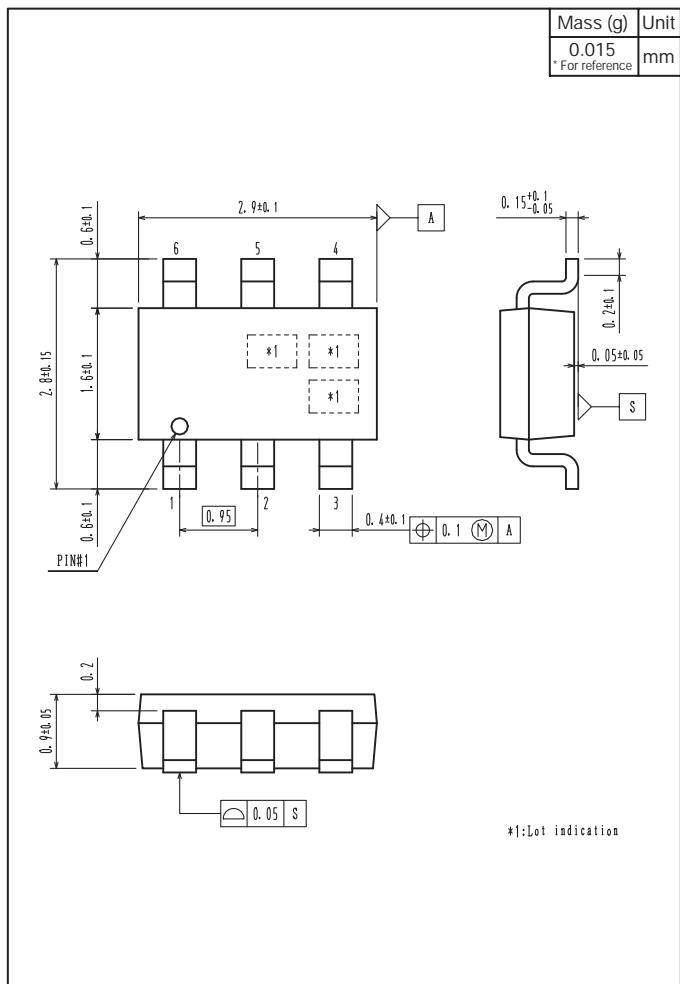
Device	Package	Shipping	memo
CPH6355-TL-H	CPH6	3,000pcs./reel	Pb Free and Halogen Free



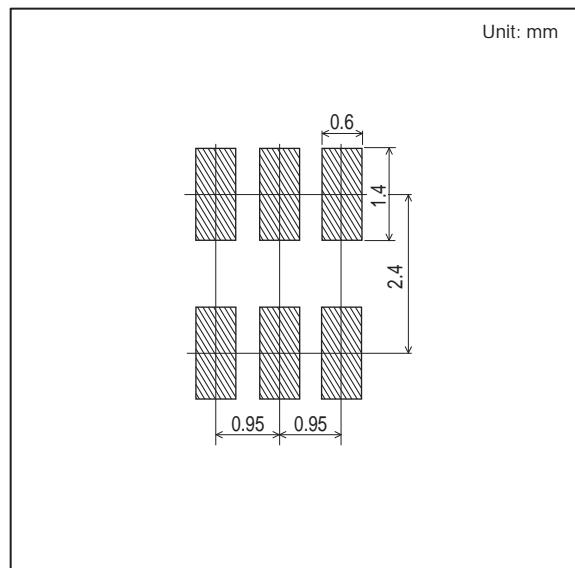


Outline Drawing

CPH6355-TL-H



Land Pattern Example



Note on usage : Since the CPH6355 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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